TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

MT6L04AE

VHF~UHF Band Low Noise Amplifier Applications

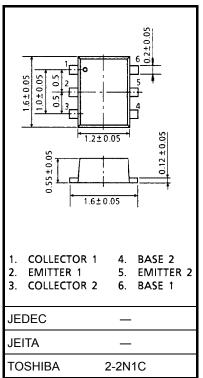
• Two devices are built in to the super-thin and extreme super mini (6 pins) package: ES6

Mounted Devices

	Q1/Q2: SSM (TESM)
Three-pins (SSM/TESM) mold products are corresponded.	MT3S04AS (MT3S04AT)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Q1/Q2	Unit	
Collector-base voltage	V _{CBO}	10	V	
Collector-emitter voltage	V _{CEO}	5	V	
Emitter-base voltage	V _{EBO}	2	V	
Collector current	Ι _C	40	mA	
Base current	Ι _Β	10	mA	
Collector power dissipation	P _C (Note 1)	100	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	



Weight: 0.003 g (typ.)

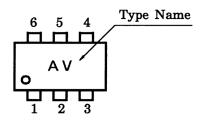
Note: Using continuously under heavy loads (e.g. the application of

high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

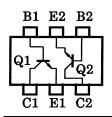
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total power dissipation of Q1 and Q2.

Marking



Pin Assignment (top view)



Unit: mm

Electrical Characteristics Q1/Q2 (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current	I _{CBO}	$V_{CB} = 5 \text{ V}, \text{ I}_{E} = 0$	_	_	0.1	μA	
Emitter cut-off current	I _{EBO}	$V_{EB} = 1 V, I_{C} = 0$	_	_	1	μA	
DC current gain	h _{FE}	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}$		_	160		
Transition frequency	f _T (1)	$V_{CE} = 1 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$	2	4.5	—	GHz	
	f _T (2)	$V_{CE} = 3 \text{ V}, \text{ I}_{C} = 7 \text{ mA}$	5	7	—	GI1Z	
Insertion gain	S _{21e} ² (1)	$V_{CE} = 1 \text{ V}, \text{ I}_{C} = 5 \text{ mA}, \text{ f} = 1 \text{ GHz}$	_	8.5	—	dB	
	S _{21e} ² (2)	V_{CE} = 3 V, I _C = 20 mA, f = 1 GHz	7.5	11	—	uВ	
Noise figure	NF (1)	$V_{CE} = 1 \text{ V}, \text{ I}_{C} = 5 \text{ mA}, \text{ f} = 1 \text{ GHz}$	_	1.3	2.2	dB	
	NF (2)	$V_{CE} = 3 \text{ V}, \text{ I}_{C} = 7 \text{ mA}, \text{ f} = 1 \text{ GHz}$	_	1.2	2		
Reverse transfer capacitance	C _{re}	$V_{CB}=1~V,~I_{E}=0,~f=1~MHz~~(Note~2)$		0.9	1.25	pF	

Note 2: Cre is measured by 3 terminal method with capacitance bridge.

Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
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